

Quad 2-input EXCLUSIVE-OR gate**74LVC86A****FEATURES**

- 5 V tolerant inputs, for interfacing with 5 V logic
- Supply voltage range from 1.2 to 3.6 V
- CMOS low power consumption
- Direct interface with TTL levels
- Inputs accept voltage up to 5.5 V
- Complies with JEDEC standard no. 8-1A
- ESD protection:
HBM EIA/JESD22-A114-A exceeds 2000 V
MM EIA/JESD22-A115-A exceeds 200 V.
- Specified from -40 to +85 °C and -40 to +125 °C.

DESCRIPTION

The 74LVC86A is a high-performance, low-power, low-voltage, Si-gate CMOS device and superior to most advanced CMOS compatible TTL families.

Inputs can be driven from either 3.3 or 5 V devices. This feature allows the use of these devices as translators in a mixed 3.3 and 5 V environment.

The 74LVC86A provides the 2-input EXCLUSIVE-OR function.

QUICK REFERENCE DATA

GND = 0 V; $T_{amb} = 25^\circ\text{C}$; $t_r = t_f \leq 2.5 \text{ ns}$.

SYMBOL	PARAMETER	CONDITIONS	TYPICAL	UNIT
t_{PHL}/t_{PLH}	propagation delay nA, nB to nY	$C_L = 50 \text{ pF}$; $V_{CC} = 3.3 \text{ V}$	3.0	ns
C_I	input capacitance		5.0	pF
C_{PD}	power dissipation capacitance per gate	$V_{CC} = 3.3 \text{ V}$; notes 1 and 2	20	pF

Notes

1. C_{PD} is used to determine the dynamic power dissipation (P_D in μW).

$$P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \sum(C_L \times V_{CC}^2 \times f_o) \text{ where:}$$

f_i = input frequency in MHz;

f_o = output frequency in MHz;

C_L = output load capacitance in pF;

V_{CC} = supply voltage in Volts;

N = total load switching outputs;

$\Sigma(C_L \times V_{CC}^2 \times f_o)$ = sum of the outputs.

2. The condition is $V_I = \text{GND}$ to V_{CC} .

FUNCTION TABLE

See note 1.

INPUT		OUTPUT
nA	nB	nY
L	L	L
L	H	H
H	L	H
H	H	L

Note

1. H = HIGH voltage level;

L = LOW voltage level.

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ORDERING INFORMATION

TYPE NUMBER	PACKAGE				
	TEMPERATURE RANGE	PINS	PACKAGE	MATERIAL	CODE
74LVC86AD	–40 to +125 °C	14	SO14	plastic	SOT108-1
74LVC86ADB	–40 to +125 °C	14	SSOP14	plastic	SOT337-1
74LVC86APW	–40 to +125 °C	14	TSSOP14	plastic	SOT402-1
74LVC86ABQ	–40 to +125 °C	14	DHVQFN14	plastic	SOT762-1

PINNING

PIN	SYMBOL	DESCRIPTION
1	1A	data input
2	1B	data input
3	1Y	data output
4	2A	data input
5	2B	data input
6	2Y	data output
7	GND	ground (0 V)
8	3Y	data output
9	3A	data input
10	3B	data input
11	4Y	data output
12	4A	data input
13	4B	data input
14	V _{CC}	supply voltage

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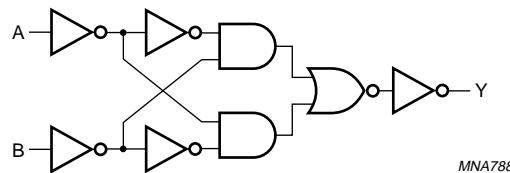


Fig.5 Logic diagram (one gate).

RECOMMENDED OPERATING CONDITIONS

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V_{CC}	supply voltage	for maximum speed performance	2.7	3.6	V
		for low-voltage applications	1.2	3.6	V
V_I	input voltage		0	5.5	V
V_O	output voltage		0	V_{CC}	V
T_{amb}	operating ambient temperature	in free air	-40	+125	°C
t_r, t_f	input rise and fall times	$V_{CC} = 1.2$ to 2.7 V	0	20	ns/V
		$V_{CC} = 2.7$ to 3.6 V	0	10	ns/V

LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 60134); voltages are referenced to GND (ground = 0 V).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V_{CC}	supply voltage		-0.5	+6.5	V
I_{IK}	input diode current	$V_I < 0$	-	-50	mA
V_I	input voltage	note 1	-0.5	+6.5	V
I_{OK}	output diode current	$V_O > V_{CC}$ or $V_O < 0$	-	± 50	mA
V_O	output voltage	note 1	-0.5	$V_{CC} + 0.5$	V
I_O	output source or sink current	$V_O = 0$ to V_{CC}	-	± 50	mA
I_{CC}, I_{GND}	V_{CC} or GND current		-	± 100	mA
T_{stg}	storage temperature		-65	+150	°C
P_{tot}	power dissipation	$T_{amb} = -40$ to +125 °C; note 2	-	500	mW

Notes

1. The input and output voltage ratings may be exceeded if the input and output current ratings are observed.
2. For SO14 packages: above 70 °C the value of P_{tot} derates linearly with 8 mW/K.
For (T)SSOP14 packages: above 60 °C the value of P_{tot} derates linearly with 5.5 mW/K.
For DHVQFN14 packages: above 60 °C the value of P_{tot} derates linearly with 4.5 mW/K.

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DC CHARACTERISTICS

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

SYMBOL	PARAMETER	TEST CONDITIONS		MIN.	TYP.	MAX.	UNIT
		OTHER	V _{CC} (V)				
T_{amb} = -40 to +85 °C; note 1							
V _{IH}	HIGH-level input voltage		1.2	V _{CC}	-	-	V
			2.7 to 3.6	2.0	-	-	V
V _{IL}	LOW-level input voltage		1.2	-	-	GND	V
			2.7 to 3.6	-	-	0.8	V
V _{OH}	HIGH-level output voltage	V _I = V _{IH} or V _{IL} I _O = -100 µA I _O = -12 mA I _O = -18 mA I _O = -24 mA	2.7 to 3.6	V _{CC} - 0.2	V _{CC}	-	V
			2.7	V _{CC} - 0.5	-	-	V
			3.0	V _{CC} - 0.6	-	-	V
			3.0	V _{CC} - 0.8	-	-	V
V _{OL}	LOW-level output voltage	V _I = V _{IH} or V _{IL} I _O = 100 µA I _O = 12 mA I _O = 24 mA	2.7 to 3.6	-	GND	0.20	V
			2.7	-	-	0.40	V
			3.0	-	-	0.55	V
I _{LI}	input leakage current	V _I = 5.5 V or GND	3.6	-	±0.1	±5	µA
I _{CC}	quiescent supply current	V _I = V _{CC} or GND; I _O = 0	3.6	-	0.1	10	µA
ΔI _{CC}	additional quiescent supply current per input pin	V _I = V _{CC} - 0.6 V; I _O = 0	2.7 to 3.6	-	5	500	µA

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SYMBOL	PARAMETER	TEST CONDITIONS		MIN.	TYP.	MAX.	UNIT
		OTHER	V _{CC} (V)				
T_{amb} = -40 to +125 °C							
V _{IH}	HIGH-level input voltage		1.2	V _{CC}	—	—	V
			2.7 to 3.6	2.0	—	—	V
V _{IL}	LOW-level input voltage		1.2	—	—	GND	V
			2.7 to 3.6	—	—	0.8	V
V _{OH}	HIGH-level output voltage	V _I = V _{IH} or V _{IL} I _O = -100 µA I _O = -12 mA I _O = -18 mA I _O = -24 mA	2.7 to 3.6	V _{CC} - 0.3	—	—	V
			2.7	V _{CC} - 0.65	—	—	V
			3.0	V _{CC} - 0.75	—	—	V
			3.0	V _{CC} - 1.0	—	—	V
V _{OL}	LOW-level output voltage	V _I = V _{IH} or V _{IL} I _O = 100 µA I _O = 12 mA I _O = 24 mA	2.7 to 3.6	—	—	0.3	V
			2.7	—	—	0.6	V
			3.0	—	—	0.8	V
I _{LI}	input leakage current	V _I = 5.5 V or GND	3.6	—	—	±20	µA
I _{CC}	quiescent supply current	V _I = V _{CC} or GND; I _O = 0	3.6	—	—	40	µA
ΔI _{CC}	additional quiescent supply current per input pin	V _I = V _{CC} - 0.6 V; I _O = 0	2.7 to 3.6	—	—	5000	µA

Note

1. All typical values are measured at V_{CC} = 3.3 V and T_{amb} = 25 °C.

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AC CHARACTERISTICS

 $V_{CC} = 0 \text{ V}$; $t_r = t_f \leq 2.5 \text{ ns}$.

SYMBOL	PARAMETER	TEST CONDITIONS		MIN.	TYP.	MAX.	UNIT
		WAVEFORMS	$V_{CC} (\text{V})$				
$T_{amb} = -40 \text{ to } +85 \text{ }^{\circ}\text{C}$; note 1							
t_{PHL}/t_{PLH}	propagation delay nA, nB to nY	see Figs 6 and 7	1.2	—	11	—	ns
			2.7	1.0	3.4	5.8	ns
			3.0 to 3.6	1.0	3.0 ⁽²⁾	5.0	ns
$t_{sk(0)}$	skew	note 3	3.0 to 3.6	—	—	1.0	ns
$T_{amb} = -40 \text{ to } +125 \text{ }^{\circ}\text{C}$							
t_{PHL}/t_{PLH}	propagation delay nA, nB to nY	see Figs 6 and 7	1.2	—	—	—	ns
			2.7	1.0	—	9.0	ns
			3.0 to 3.6	1.0	—	6.5	ns
$t_{sk(0)}$	skew	note 3	3.0 to 3.6	—	—	1.5	ns

Notes

1. All typical values are measured at $T_{amb} = 25 \text{ }^{\circ}\text{C}$.
2. This typical value is measured at $V_{CC} = 3.3 \text{ V}$.
3. Skew between any two outputs of the same package switching in the same direction. This parameter is guaranteed by design.

AC WAVEFORMS

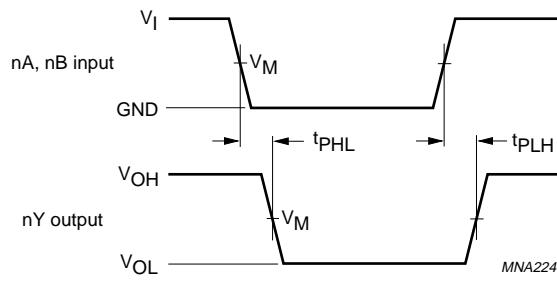
 $V_M = 1.5 \text{ V}$ at $V_{CC} \geq 2.7 \text{ V}$. $V_M = 0.5V_{CC}$ at $V_{CC} < 2.7 \text{ V}$. V_{OL} and V_{OH} are typical output voltage drop that occur with the output load.

Fig.6 The inputs nA and nB to output nY propagation delay.

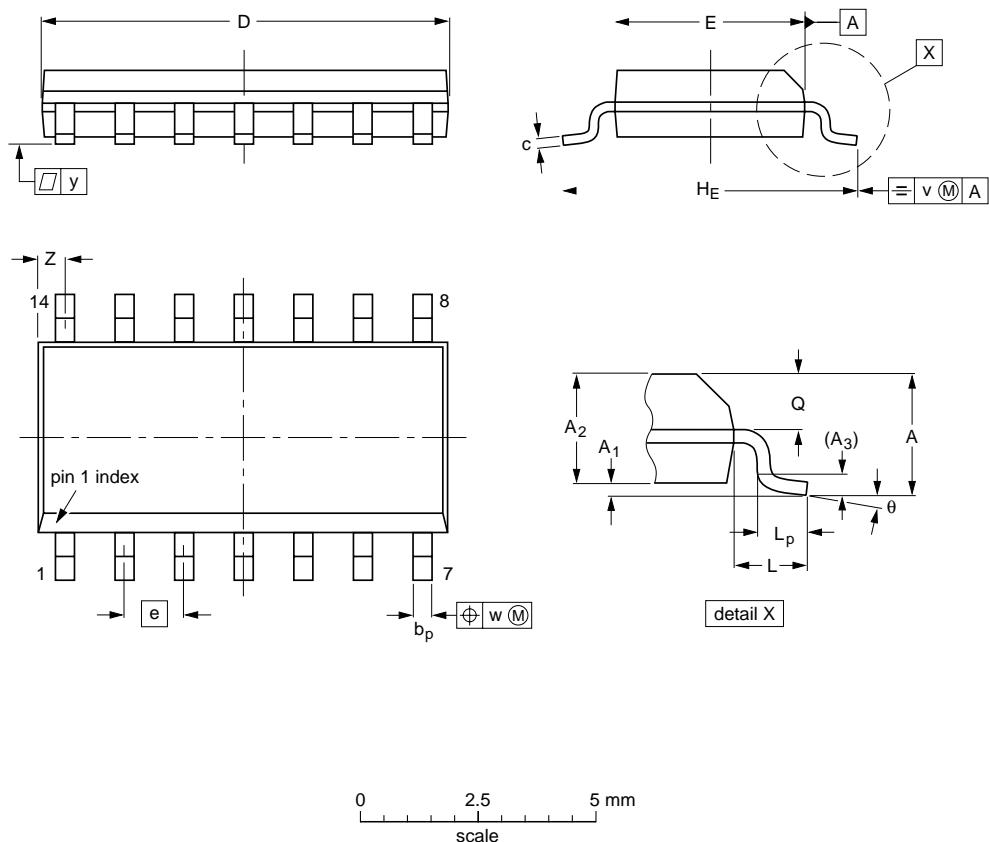
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PACKAGE OUTLINES

SO14: plastic small outline package; 14 leads; body width 3.9 mm

SOT108-1



DIMENSIONS (inch dimensions are derived from the original mm dimensions)

UNIT	A max.	A ₁	A ₂	A ₃	b _p	c	D ⁽¹⁾	E ⁽¹⁾	e	H _E	L	L _p	Q	v	w	y	z ⁽¹⁾	θ
mm	1.75 0.10	0.25 1.45 0.10	1.45 1.25	0.25	0.49 0.36	0.25 0.19	8.75 8.55	4.0 3.8	1.27	6.2 5.8	1.05	1.0 0.4	0.7 0.6	0.25	0.25	0.1	0.7 0.3	8°
inches	0.069 0.004	0.010 0.049	0.057 0.049	0.01	0.019 0.014	0.0100 0.0075	0.35 0.34	0.16 0.15	0.05	0.244 0.228	0.041	0.039 0.016	0.028 0.024	0.01	0.01	0.004	0.028 0.012	0°

Note

1. Plastic or metal protrusions of 0.15 mm (0.006 inch) maximum per side are not included.

OUTLINE VERSION	REFERENCES				EUROPEAN PROJECTION	
	IEC	JEDEC	JEITA			
SOT108-1	076E06	MS-012				